



R U N A U

Jiangsu Runau Electronics Manufacturing Co.,Ltd

ZP2000-Rectifier Diode

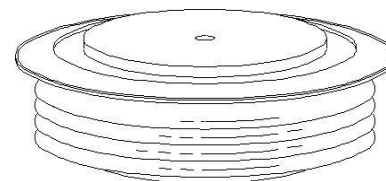
2500 - 3500 V_{RRM}

GENERAL PURPOSE HIGH POWER STANDARD RECTIFIER

Features:

- . All Diffused Structure
- . High Surge rating
- . Blocking capability up to 3500 volts
- . Ceramic Housing Hermetic Package
- . Pressure Assembled Device

ZT65cT



ELECTRICAL CHARACTERISTICS AND RATINGS

Reverse Blocking

Device Type	V _{RRM} (1)	V _{RSM} (1)
ZP2000-25	2500	2700
ZP2000-26	2600	2800
ZP2000-28	2800	3000
ZP2000-30	3000	3200
ZP2000-32	3200	3400
ZP2000-35	3500	3700

Notes:

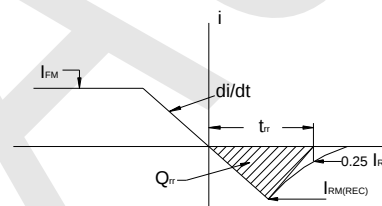
All ratings are specified for T_j=25 °C unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range 0 to +150 °C.

(2) 10 msec. max. pulse width

(3) Maximum value for T_j = 150 °C.

(4) See parameter definition below:



REVERSE RECOVERY CHARACTERISTIC

V_{RRM} = Repetitive peak reverse voltage

V_{RSM} = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	I _{RRM}	5 mA 60 mA (3)
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Conducting - on state

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average forward current	I _{F(AV)}		2000		A	Sinewave, 180°, T _c = 90°C
RMS forward current	I _{FRMS}		3140		A	Nominal value
Peak one cycle surge (non repetitive) current	I _{FSM}		28000		A	10 msec (50Hz), sinusoidal wave-shape, 180° conduction, T _j = 150 °C
I square t	I ² t		4 × 10 ⁶		A ² s	10 msec
Peak forward voltage	V _{FM}		1.55		V	I _{FM} = 3000A; T _j = 25°C
Threshold voltage	V _{FO}		0.86		V	T _j = 150°C, I = 0.5π I _{F(AV)} to 1.5π I _{F(AV)}
Threshold voltage, Low-level	r _F		0.16		mΩ	T _j = 150°C, I = 0.5π I _{F(AV)} to 1.5π I _{F(AV)}
Reverse Recovery Current (4)	I _{RM(REC)}				A	I _{FM} = 500 A; di/dt = -10 A/s; T _{jmax}
Reverse Recovery Charge (4)	Q _{rr}			5000	μC	I _{FM} = 500 A; di/dt = -10 A/s; T _{jmax}
Reverse Recovery Time (4)	t _{rr}				μs	I _{FM} = 500 A; di/dt = -10 A/s; T _{jmax}

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T_j	-40	+150		$^{\circ}\text{C}$	
Storage temperature	T_{stg}	-40	+150		$^{\circ}\text{C}$	
Thermal resistance - junction to case	$R_{\Theta(j-c)}$		0.015		$^{\circ}\text{C/W}$	Double sided cooled
Thermal resistance - case to heatsink	$R_{\Theta(c-s)}$		0.0045		$^{\circ}\text{C/W}$	Double sided cooled
Mounting force	P	27	33	30	kN	
Weight	W			0.72	kg.	

* Mounting surfaces smooth, flat and greaseless

CASE OUTLINE AND DIMENSIONS

